

6501130 NATL SEMICOND, (DISCRETE)

28C 35511 D

T-29-01

Pro Electron Series

PRO ELECTRON SERIES (Bipolar—see page 5-37 for JFET)

Type No.	Case Style	V _{CE0} [*] (V) Min	V _{CE0} [*] (V) Min	V _{EB0} (V) Min	I _{CE0} [*] (mA) Max	V _{CB} (V)	HFE I _{fe} 1 kHz [*] Min	HFE I _{fe} 1 kHz [*] Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC107	TO-18	45	6	50	15 [*]	50	40	0.01	0.6	0.55	100	4.5	150	10		10	1	04
BC107A	TO-18	45	6	50	15 [*]	50	125	500 [*]	0.2	0.55	10	4.5	150	10		10	1	04
BC107B	TO-18	45	6	50	15 [*]	50	40	0.01	0.6	0.55	100	4.5	150	10		10	1	04
BC108	TO-18	20	5	30	15 [*]	30	240	500 [*]	0.2	0.55	10	4.5	150	10		10	1	04
BC108A	TO-18	20	5	30	15 [*]	30	40	0.01	0.6	0.55	100	4.5	150	10		10	1	04
BC108B	TO-18	20	5	30	15 [*]	30	125	260 [*]	0.2	0.55	100	4.5	150	10		10	1	04
BC108C	TO-18	20	5	30	15 [*]	30	40	0.01	0.6	0.55	10	4.5	150	10		10	1	04
BC109	TO-18	20	5	30	15 [*]	30	40	0.01	0.6	0.55	100	4.5	150	10		10	1	04
BC109B	TO-18	20	5	30	15 [*]	30	240	500 [*]	0.2	0.55	10	4.5	150	10		10	1	04
BC109C	TO-18	20	5	30	15 [*]	30	40	0.01	0.6	0.55	100	4.5	150	10		10	1	04
BC140	TO-39	40	7	80 [*]	100 [*]	60	100	100 [*]	1.0	1.8 [*]	1A	25	50	50	850		2	14
BC140-6	TO-39	40	7	80 [*]	100 [*]	60	240	900 [*]	1.0	1.8 [*]	1A	25	50	50	850		2	14
BC140-10	TO-39	40	7	80 [*]	100 [*]	60	100	100 [*]	1.0	1.8 [*]	1A	25	50	50	850		2	14
BC140-16	TO-39	40	7	80 [*]	100 [*]	60	100	100 [*]	1.0	1.8 [*]	1A	25	50	50	850		2	14
BC141	TO-39	60	7	100 [*]	100 [*]	60	40	250	1.0	1.8 [*]	1A	25	50	50	850		2	14
BC141-6	TO-39	60	7	100 [*]	100 [*]	60	40	100	1.0	1.8 [*]	1A	25	50	50	850		2	14
BC141-10	TO-39	60	7	100 [*]	100 [*]	60	63	160	1.0	1.8 [*]	1A	25	50	50	850		2	14

6501130 NATL SEMICOND, (DISCRETE)

28C 35512

D



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	IC _{ES} [*] IC _{BO} (mA) Max	H _{FE} h _{FE} @ 1 kHz Min Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min Max	IC (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC143	TO-5	60	60	5	50	20	1.5	1.5	500	20	60				63
BC146-1	TO-92 (94)	20	20	4	50	80	1.5	1.5	500	20	60				04
BC146-2	TO-92 (94)	20	20	4	50	140	1.5	1.5	500	20	60				04
BC146-3	TO-92 (94)	20	20	4	50	280	1.5	1.5	500	20	60				04
BC160	TO-39	40*	5	40	100	40	1.0	1.7*	1A	30	50	650		2	67
BC160-6	TO-39	40*	5	40	100	40	1.0	1.7*	1A	30	50	650		2	67
BC160-10	TO-39	40*	5	40	100	63	1.0	1.7*	1A	30	50	650		2	67
BC160-16	TO-39	40*	5	40	100	100	1.0	1.7*	1A	30	50	650		2	67
BC161	TO-39	60*	5	60	100	40	1.0	1.7*	1A	30	50	650		2	67
BC161-6	TO-39	60*	5	60	100	40	1.0	1.7*	1A	30	50	650		2	67
BC161-10	TO-39	60*	5	60	100	63	1.0	1.7*	1A	30	50	650		2	67
BC161-16	TO-39	60*	5	60	100	100	1.0	1.7*	1A	30	50	650		2	67
BC167	TO-92 (94)	60*	45	6	15*	110	0.2	0.55	10	4.5	150		10	1	04
BC167A	TO-92 (94)	60*	45	6	15*	125	0.6	0.55	100	4.5	150		10	1	04
BC167B	TO-92 (94)	60*	45	6	15*	110	0.2	0.55	10	4.5	150		10	1	04
BC168	TO-92 (94)	20	20	5	15*	110	0.2	0.55	10	4.5	150		10	1	04
BC168A	TO-92 (94)	20	20	5	15*	125	0.6	0.55	100	4.5	150		10	1	04
BC168B	TO-92 (94)	20	20	5	15*	110	0.2	0.55	10	4.5	150		10	1	04

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TEST CONDITIONS:
 (1) IC = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) IC = 100 mA, V_{CE} = 20V, IB¹ = IB² = 5 mA. (3) IC = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) IC = 100 mA, V_{CE} = 10V, IB¹ = IB² = 10 mA. (5) IC = 10 mA, V_{CE} = 3V, IB¹ = IB² = 1 mA. (6) IC = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) IC = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) IC = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) IC = 150 mA, V_{CE} = 6V, IB¹ = IB² = 15 mA. (10) IC = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35513 D

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PRO ELECTRON SERIES (Continued)



Type No.	Case Style	VCES* VCBO (V) Min	VCEO (V) Min	VEBO (V) Min	ICES* ICBO (mA) Max	HFE hfe 1 kHz* Min Max	VCE(SAT) (V) Max	VBE(SAT) & VBE(ON)* (V)		Cob (pF) Max	fT (MHz) Min Max	toff (ns) Max	NF (dB) Max	Test Conditions	Process No.
								Min	Max						
BC168C	TO-92 (94)		20	5	15*	110 450	0.2 0.6	0.55	0.70* 2	4.5	150		10	1	04
BC169	TO-92 (94)		20	5	15*	110 240	0.2 0.6	0.55	0.70* 2	4.5	150		4	1	04
BC169B	TO-92 (94)		20	5	15*	110 240	0.2 0.6	0.55	0.70* 2	4.5	150		4	1	04
BC169C	TO-92 (94)		20	5	15*	110 450	0.2 0.6	0.55	0.70* 2	4.5	150		4	1	04
BC177	TO-18	50	45	5	100	110 125	0.18		0.78 10 0.75* 2 1.0* 100	4.5	150		10	1	71
BC177A	TO-18	50	45	5	100	110 125	0.18		0.78 10 0.75* 2 1.0* 100	4.5	150		10	1	71
BC177B	TO-18	50	45	5	100	110 240	0.18		0.78 10 0.75* 2 1.0* 100	4.5	150		10	1	71
BC177VI	TO-18	50	45	5	100	110 75	0.18		0.78 10 0.75* 2 1.0* 100	4.5	150		10	1	71
BC178	TO-18	30	25	5	100	110 125	0.18		0.78 10 0.75* 2 1.0* 100	4.5	150		10	1	71
BC178A	TO-18	30	25	5	100	110 125	0.18		0.78 10 0.75* 2 1.0* 100	4.5	150		10	1	71
BC178B	TO-18	30	25	5	100	110 240	0.18		0.78 10 0.75* 2 1.0* 100	4.5	150		10	1	71
BC179	TO-18	25	20	5	100	110 125	0.18		0.78 10 0.75* 2 1.0* 100	4.5	150		4	1	71
BC179A	TO-18	25	20	5	100	110 125	0.18		0.78 10 0.75* 2 1.0* 100	4.5	150		4	1	71

6501130 NATL SEMICOND, (DISCRETE)

28C 35514

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PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE5} [*] V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EBO} (V) Min	I _{CE5} [*] I _{CB0} (mA) Max	HFE h _{fe} 1 kHz Min	HFE h _{fe} 1 kHz Max	I _C & V _{CE} (mA) & (V) Min	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC179B	TO-18	25	20	5	100	110	240	2	0.18	0.78	10	4.5	150	10		4	1	71
BC182	TO-92 (97)	60	50	5	15	40	80	0.01	0.6	1.2	100	5	150	10		10	1	04
BC182A	TO-92 (97)	60	50	5	15	40	80	0.01	0.6	1.2	100	5	150	10		10	1	04
BC182B	TO-92 (97)	60	50	5	15	40	80	0.01	0.6	1.2	100	5	150	10		10	1	04
BC182L	TO-92 (94)	60	50	5	15	40	80	0.01	0.6	1.2	100	5	150	10		10	1	04
BC182LA	TO-92 (94)	60	50	5	15	40	80	0.01	0.6	1.2	100	5	150	10		10	1	04
BC182LB	TO-92 (94)	60	50	5	15	40	80	0.01	0.6	1.2	100	5	150	10		10	1	04
BC183	TO-92 (97)	45	30	5	15	40	80	0.01	0.6	1.2	100	5	150	10		10	1	04
BC183A	TO-92 (97)	45	30	5	15	40	80	0.01	0.6	1.2	100	5	150	10		10	1	04
BC183B	TO-92 (97)	45	30	5	15	40	80	0.01	0.6	1.2	100	5	150	10		10	1	04
BC183C	TO-92 (97)	45	30	5	15	40	80	0.01	0.6	1.2	100	5	150	10		10	1	04

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35515 D

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Pro Electron Series

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} * V _{CB0} (V) Min	V _{CEO} (V) Min	V _{EB0} (V) Min	I _{CE} * I _{CB0} (nA) Max	V _{CB} (V)	H _{FE} h _{FE} @ 1 kHz*		I _C & V _{CE} (V)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)*} (V)		I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) @ Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
							Min	Max			Min	Max								
BC183L	TO-92 (94)	45	30	5	15	30	40 80 125	0.01 100 900*	5 5 5	0.6 0.25	1.2 0.55	100 10 2	5	150	10			10	1	04
BC183LA	TO-92 (94)	45	30	5	15	30	40 80 125	0.01 100 900*	5 5 5	0.6 0.25	1.2 0.55	100 10 2	5	150	10			10	1	04
BC183LB	TO-92 (94)	45	30	5	15	30	40 80 240	0.01 100 500*	5 5 5	0.6 0.25	1.2 0.55	100 10 2	5	150	10			10	1	04
BC183LC	TO-92 (94)	45	30	5	15	30	40 80 450	0.01 100 900*	5 5 5	0.6 0.25	1.2 0.55	100 10 2	5	150	10			10	1	04
BC184	TO-92 (97)	45	30	5	15	30	100 130 240	0.01 100 900*	5 5 5	0.6 0.25	1.2 0.55	100 10 2	5	150	10			4	1	04
BC184B	TO-92 (97)	45	30	5	15	30	100 130 240	0.01 100 500*	5 5 5	0.6 0.25	1.2 0.55	100 10 2	5	150	10			4	1	04
BC184C	TO-92 (97)	45	30	50	15	30	100 130 450	0.01 100 900*	5 5 5	0.6 0.25	1.2 0.55	100 10 2	5	150	10			4	1	04
BC184L	TO-92 (94)	45	30	50	15	30	100 130 240	0.01 100 900*	5 5 5	0.6 0.25	1.2 0.55	100 10 2	5	150	10			4	1	04
BC184LB	TO-92 (94)	45	30	50	15	30	100 130 240	0.01 100 500*	5 5 5	0.6 0.25	1.2 0.55	100 10 2	5	150	10			4	1	04
BC184LC	TO-92 (94)	45	30	50	15	30	100 130 450	0.01 100 900*	5 5 5	0.6 0.25	1.2 0.55	100 10 2	5	150	10			4	1	04
BC204	TO-92 (92)	50	45	5	50	45	50	450	2	5	0.3	10						10	1	71
BC207	TO-92 (92)	50	45	5	15	40	110	450	2	5	0.25 0.6	10 100	6					10	1	04
BC212	TO-92 (97)	60	50	5	15	30	60	400*	2	5	0.6 0.25	1.1 0.6	10 10	200	10			10	1	63

6501130 NATL SEMICOND, (DISCRETE)

28C 35516

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PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} * V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CE} * I _{CB0} (mA) Max	HFE h _{FE} 1 kHz* Min	I _C & V _{CE} (mA) (V) Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)*} (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC212A	TO-92 (97)	60	50	5	15	100	300* 2 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC212B	TO-92 (97)	60	50	5	15	200	400* 2 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC212L	TO-92 (94)	60	50	5	15	40 60 60*	0.01 2 5 2 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC212LA	TO-92 (94)	60	50	5	15	40 60 100	0.01 2 5 300* 2 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC212LB	TO-92 (94)	60	50	5	15	40 60 200	0.01 2 5 400* 2 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC213	TO-92 (97)	45	30	5	15	40 60 80	0.01 2 5 600* 2 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC213A	TO-92 (97)	45	30	5	15	40 60 100	0.01 2 5 300* 2 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC213B	TO-92 (97)	45	30	5	15	40 60 200	0.01 2 5 400* 2 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC213C	TO-92 (97)	45	30	5	15	40 60 350	0.01 2 5 600* 2 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC213L	TO-92 (94)	45	30	5	15	40 80 80*	0.01 2 5 400 2 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC213LA	TO-92 (94)	45	30	5	15	40 80 100	0.01 2 5 300* 2 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 μA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

D

Pro Electron Series

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35517 D

T-29-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} [*] (V)		V _{BE0} (V)	I _{CE0} [*] (mA)		H _{FE} I _{hfe} @ 1 kHz [*]	I _C & V _{CE} (V)		V _{CE(SAT)} (V) & V _{BE(ON)} [*] (V)		I _C (mA)		C _{ob} (pF)	f _T (MHz)		t _{off} (ns)	NF (dB)	Test Conditions	Process No.
		Min	Max		Min	Max		Min	Max	Min	Max	Min	Max		Min	Max				
BC213LB	TO-92 (94)	30	45	5	15	30	40	0.01	5	0.6	1.1	100	10	10	200	10	1	63		
BC213LC	TO-92 (94)	30	45	5	15	30	200	400 [*]	2	0.25	0.6	0.72 [*]	2	10	200	10	1	63		
BC214	TO-92 (97)	30	45	5	15	30	350	600 [*]	2	0.6	1.1	100	10	10	200	10	1	63		
BC214A	TO-92 (97)	30	45	5	15	30	140	600 [*]	2	0.6	1.1	100	10	10	200	10	1	63		
BC214B	TO-92 (97)	30	45	5	15	30	40	0.01	5	0.6	1.1	100	10	10	200	10	1	63		
BC214C	TO-92 (97)	30	45	5	15	30	200	400 [*]	2	0.25	0.6	0.72 [*]	2	10	200	10	1	63		
BC214L	TO-92 (94)	30	45	5	15	30	40	0.01	5	0.6	1.1	100	10	10	200	10	1	63		
BC214LB	TO-92 (94)	30	45	5	15	30	350	600 [*]	2	0.25	0.6	0.72 [*]	2	10	200	10	1	63		
BC214LC	TO-92 (94)	30	45	5	15	30	100	0.01	5	0.6	1.1	100	10	10	200	10	1	63		
BC237-92	TO-92 (97)	45	50	6	50	20	140	2	5	0.25	0.6	0.72 [*]	2	4.5	200	10	1	04		
BC237A-92	TO-92 (97)	45	50	6	50	20	125	500 [*]	2	0.25	0.55	0.70 [*]	2	4.5	200	10	1	04		

6501130 NATL SEMICOND, (DISCRETE)

28C 35518
T-24-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	VCES* V _{CE0} (V) Min	VEBO (V) Min	ICES* I _{CB0} (mA) Max	HFE h _{FE} @ 1 kHz*	VCE(SATI) & VBE(ON)* (V) Max	VBE(SATI) & VBE(ON)* (V) Min	C _{db} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.			
															I _C & V _{CE} (mA) (V) Max	I _C (mA) Max	I _C (mA) Max
BC237B-92	TO-92 (97)	50	45	50	100	0.25	0.77*	4.5		10		10	1	04			
					140										0.01	0.6	100
					240										500*	0.55	0.70*
BC238-92	TO-92 (97)	30	20	50	100	0.25	0.77*	4.5		10		10	1	04			
					140										2	0.6	100
					120										100	0.55	0.70*
BC238A-92	TO-92 (97)	30	20	50	100	0.25	0.77*	4.5		10		10	1	04			
					140										2	0.6	100
					120										100	0.55	0.70*
BC238B-92	TO-92 (97)	30	20	50	100	0.25	0.77*	4.5		10		10	1	04			
					140										2	0.6	100
					120										100	0.55	0.70*
BC238C-92	TO-92 (97)	30	20	50	100	0.25	0.77*	4.5		10		10	1	04			
					140										2	0.6	100
					120										100	0.55	0.70*
BC239-92	TO-92 (97)	30	20	50	100	0.25	0.77*	4.5		10		4	1	04			
					140										2	0.6	100
					120										100	0.55	0.70*
BC239B-92	TO-92 (97)	30	20	50	100	0.25	0.77*	4.5		10		4	1	04			
					140										2	0.6	100
					120										100	0.55	0.70*
BC239C-92	TO-92 (97)	30	20	50	100	0.25	0.77*	4.5		10		4	1	04			
					140										2	0.6	100
					120										100	0.55	0.70*
BC281A	TO-18	45		50	100	0.25	0.9	4.5		10		6	3	71			
					140										2	0.6	100
					120										100	0.55	0.70*

TEST CONDITIONS:
 (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35519 D

T-29-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB} [*] (V) Min	V _{CE} [*] (V) Min	V _{EB} [*] (V) Min	I _{CE} [*] I _{CB} [*] (mA) Max	HFE h _{FE} 1 kHz [*] Min	HFE h _{FE} 1 kHz [*] Max	I _C & V _{CE} (mA) (V) Min	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC261B	TO-18		45		50	100	0.01	5	0.25	0.9	10					6	3	71
BC262A	TO-18		20	5	50	140	2	5	0.25	0.9	10					6	3	71
						120	100	5										
						240	500*	2										
BC262B	TO-18		20	5	50	100	0.01	5	0.25	0.9	10					6	3	71
						140	2	5										
						120	100	5										
BC263A	TO-18		20	5	50	240	500*	2	0.6		100					2.5	3	71
						140	2	5										
						120	100	5										
BC263B	TO-18		20	5	50	100	0.01	5	0.25	0.9	10					2.5	3	71
						140	2	5										
						120	100	5										
BC307-92	TO-92 (97)	50	45	5	100	240	500*	2	0.6		100					10	1	71
						140	2	5										
						120	100	5										
BC307A-92	TO-92 (97)	50	45	5	100	100	0.01	5	0.18	0.78	10					10	1	71
						140	2	5										
						120	100	5										
BC307B-92	TO-92 (97)	50	45	5	100	240	500*	2	0.18	0.78	10					10	1	71
						140	2	5										
						120	100	5										
BC308-92	TO-92 (97)	30	25	5	100	100	0.01	5	0.18	0.78	10					10	1	71
						140	2	5										
						120	100	5										
BC308A-92	TO-92 (97)	30	25	5	100	240	900*	2	0.18	0.78	10					10	1	71
						140	2	5										
						120	100	5										

6501130 NATL SEMICOND, (DISCRETE)

28C 35520

T-29-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} [*] (V) Min	V _{CE0} [*] (V) Min	V _{EB0} (V) Min	I _{CE0} [*] (mA) Max	I _{CB0} [*] (mA) Max	HFE		I _C & V _{CE}		V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V)		I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
							Min	Max	Min	Max		Min	Max								
BC308B-92	TO-92 (97)	25	30	5	100	20	100	140	0.01	5	0.18	0.78	10						10	1	71
BC308C-92	TO-92 (97)	25	30	5	100	20	100	120	0.01	5	0.18	0.75*	2						10	1	71
BC309-92	TO-92 (97)	20	25	5	100	20	100	140	0.01	5	0.18	0.78	10						4	1	71
BC309B-92	TO-92 (97)	20	25	5	100	20	100	120	0.01	5	0.18	0.75*	2						4	1	71
BC309C-92	TO-92 (97)	20	25	5	100	20	100	240	0.01	5	0.8	0.78	10						4	1	71
BC317	TO-92 (92)	45	50	6	30	20	110	125	0.01	5	0.2	0.77*	10	4					6	1	04
BC317A	TO-92 (92)	45	50	6	30	20	110	125	0.01	5	0.2	0.77*	10	4					6	1	04
BC317B	TO-92 (92)	45	50	6	30	20	200	240	0.01	5	0.2	0.77*	10	4					6	1	04
BC318	TO-92 (92)	20	30	5	30	20	110	125	0.01	5	0.2	0.77*	10	4					6	1	04
BC318A	TO-92 (92)	20	30	5	30	20	110	125	0.01	5	0.2	0.77*	10	4					6	1	04

TEST CONDITIONS:
 (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35521 D

Pro Electron Series

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} ^s V _{CB} ^s (V) Min	V _{CE} ^s (V) Min	V _{EB} ^s (V) Min	I _{CB} ^s I _{CB} ^s @ (mA) Max	HFE h _{FE} 1 kHz Min Max	V _{CE} ^s & V _{CE} (V) Min Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) (V) Min Max	I _C (mA) Min Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC318B	TO-92 (92)	30	20	5	30	200 240	450 500	0.2 0.5	0.77* 0.72*	10 100	4				6	1	04
BC318C	TO-92 (92)	30	20	5	30	100 450	800 900	0.2 0.5	0.77* 0.72*	10 100	4				6	1	04
BC319	TO-92 (92)	30	20	5	30	40 200	800 900	0.2 0.5	0.77* 0.72*	10 100	4				4	1	04
BC319B	TO-92 (92)	30	20	5	30	200 240	450 500	0.2 0.5	0.77* 0.72*	10 100	4				4	1	04
BC319C	TO-92 (92)	30	20	5	30	100 420	800 900	0.2 0.5	0.77* 0.72*	10 100	4				4	1	04
BC327	TO-92 (97)	50†	45	5	100†	40	600	0.7	12*	500	4				4	1	67
BC327-10	TO-92 (97)	50†	45	5	100†	40	160	0.7	1.2*	500	4				4	1	67
BC327-16	TO-92 (97)	50†	45	5	100†	40	250	0.7	1.2*	500	4				4	1	67
BC327-25	TO-92 (97)	50†	45	5	100†	40	400	0.7	1.2*	500	4				4	1	67
BC328	TO-92 (97)	30†	25	5	100†	40	600	0.7	1.2	500	4				4	1	67
BC328-10	TO-92 (97)	30†	25	5	100†	40	160	0.7	1.2	500	4				4	1	67
BC328-16	TO-92 (97)	30†	25	5	100†	40	250	0.7	1.2	500	4				4	1	67
BC328-25	TO-92 (97)	30†	25	5	100†	40	400	0.7	1.2	500	4				4	1	67
BC337	TO-92 (97)	50†	45	5	100†	40	600	0.7	1.2*	500	4				4	1	14
BC337-10	TO-92 (97)	50†	45	5	100†	40	160	0.7	1.2*	500	4				4	1	14
BC337-16	TO-92 (97)	50†	45	5	100†	40	250	0.7	1.2*	500	4				4	1	14
BC337-25	TO-92 (97)	50†	45	5	100†	40	400	0.7	1.2*	500	4				4	1	14

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6501130 NATL SEMICOND, (DISCRETE)

28C 35522

T-29-01



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} [*] (V) Min	V _{BE0} [*] (V) Min	I _{CB0} [*] (mA) Max	V _{CB} (V)	h _{FE} @ 1 kHz [*]		I _C & V _{CE} (mA) & (V)		V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V)		C _{cb} (pF) Max	f _T (MHz)		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
						Min	Max	I _C	V _{CE}		Min	Max		Min	Max				
BC338	TO-92 (97)	30†	5	100†	25	40	300	1	1	0.7	500	1.2*	4					1	14
BC338-10	TO-92 (97)	30†	5	100†	25	40	300	1	1	0.7	500	1.2*	4					1	14
BC338-16	TO-92 (97)	30†	5	100†	25	63	160	1	1	0.7	500	1.2*	4					1	14
BC338-25	TO-92 (97)	30†	5	100†	25	40	300	1	1	0.7	500	1.2*	4					1	14
BC415	TO-92 (97)	45	5	15	30	40	0.01	5	5	0.25	10							10	71
BC415A	TO-92 (97)	45	5	15	30	40	0.01	5	5	0.25	10							10	71
BC415B	TO-92 (97)	45	5	15	30	100	0.01	5	5	0.25	10							10	71
BC415C	TO-92 (97)	45	5	15	30	180	0.01	5	5	0.25	10							10	71
BC485	TO-92 (97)	45	5	100	30	380	0.01	5	5	0.6	100							10	71
BC485A	TO-92 (97)	45	5	100	30	15	1A	2	2	0.5	1.2	500	4					1	14
BC485B	TO-92 (97)	45	5	100	30	40	10	2	2	0.5	1.2*	300	4					1	14
BC485L	TO-92 (97)	45	5	100	30	15	1A	5	5	0.5	1.2	500	4					1	14
BC547	TO-92 (97)	50	6	10	20	125	500*	2	5	0.25	0.77*	10	4.5					1	04
BC547A	TO-92 (97)	50	6	10	20	125	260*	2	5	0.6	0.55	0.70*	4.5					1	04

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35523 D

T-29-01

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	VCES* VCBO (V) Min	VCEO (V) Min	VEBO (V) Min	ICES* ICBO (mA) Max	HFE hfe 1 kHz*		VCE(SAT) (V) Max	VBE(SAT) & VBE(ON)* (V) Min Max		Cob (pF) Max	fT (MHz) Min Max	IC (mA) Max	toff (ns) Max	NF (dB) Max	Test Conditions	Process No.
						Min	Max		Min	Max							
BC547B	TO-92 (97)	50	45	6	10	20	240	500*	2	5	0.25	0.6	0.77*	10	100	10	04
BC547C	TO-92 (97)	50	45	6	10	20	450	900*	2	5	0.25	0.6	0.77*	10	100	10	04
BC548	TO-92 (97)	30	20	5	10	20	125	900*	2	5	0.25	0.6	0.77*	10	100	10	04
BC548A	TO-92 (97)	30	20	5	10	20	125	260*	2	5	0.25	0.6	0.77*	10	100	10	04
BC548B	TO-92 (97)	30	20	5	10	20	240	500*	2	5	0.25	0.6	0.77*	10	100	10	04
BC548C	TO-92 (97)	30	20	5	10	20	450	900*	2	5	0.25	0.6	0.77*	10	100	10	04
BC549	TO-92 (97)	30	20	5	10	20	240	900*	2	5	0.25	0.6	0.77*	10	100	4	04
BC549B	TO-92 (97)	30	20	5	10	20	240	500*	2	5	0.25	0.6	0.77*	10	100	4	04
BC549C	TO-92 (97)	30	20	5	10	20	450	900*	2	5	0.25	0.6	0.77*	10	100	4	04
BC550	TO-92 (97)	50	45	5	10	45	240	900*	2	5	0.25	0.6	0.77*	10	100	3	04
BC550B	TO-92 (97)	50	45	5	10	45	240	500*	2	5	0.25	0.6	0.77*	10	100	3	04
BC550C	TO-92 (97)	50	45	5	10	45	450	900*	2	5	0.25	0.6	0.77*	10	100	3	04
BC557	TO-92 (97)	50	45	5	100	20	75	260*	2	5	0.3	0.65	0.82*	10	100	10	71

6501130 NATL SEMICOND, (DISCRETE)

28C 35524

T-29-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} * VCBO (V) Min	V _{CEO} (V) Min	V _{EB0} (V) Min	I _{CE} * I _{CB0} (mA) Max	HFE h _{FE} @ 1 kHz* Min Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)*} (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC557A	TO-92 (97)	50	45	5	100	20	0.3 0.65	0.82* 0.6	10 100					10	1	71
BC557B	TO-92 (97)	50	45	5	100	20	0.3 0.65	0.82* 0.6	10 100					10	1	71
BC558	TO-92 (97)	30	25	5	100	20	0.3 0.65	0.82* 0.6	10 100					10	1	71
BC558A	TO-92 (97)	30	25	5	100	20	0.3 0.65	0.82* 0.6	10 100					10	1	71
BC558B	TO-92 (97)	30	25	5	100	20	0.3 0.65	0.82* 0.6	10 100					10	1	71
BC558C	TO-92 (97)	30	25	5	100	20	0.3 0.65	0.82* 0.6	10 100					10	1	71
BC559	TO-92 (97)	25	20	5	100	20	0.3 0.65	0.82* 0.6	10 100					4	1	71
BC559A	TO-92 (97)	25	20	5	100	20	0.3 0.65	0.82* 0.6	10 100					4	1	71
BC559B	TO-92 (97)	25	20	5	100	20	0.3 0.65	0.82* 0.6	10 100					4	1	71
BC559C	TO-92 (97)	25	20	5	100	20	0.3 0.65	0.82* 0.6	10 100					4	1	71
BC560	TO-92 (97)	50	45	5	100	45	0.3 0.65	0.82* 0.6	10 100					2	1	71

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CC} = 20V, I_B = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CC} = 10V, I_B = I_B² = 10 mA. (5) I_C = 10 mA, V_{CC} = 3V, I_B = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CC} = 6V, I_B = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35525 D

T-29-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} [*] (V) Min	V _{CE0} [*] (V) Max	V _{BE0} (V) Min	V _{BE0} (V) Max	I _{CE0} [*] (mA) Max	I _{CE0} [*] (mA) Max	HFE h _{FE} 1 kHz [*] Min	HFE h _{FE} 1 kHz [*] Max	I _C & V _{CE} (mA) & (V) Min	I _C & V _{CE} (mA) & (V) Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Max	V _{CE(SAT)} (V) Min	V _{BE(SAT)} (V) Min	I _C (mA) Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.	
BC560A	TO-92 (97)	45	50	5	45	100	100	125	260*	2	5	0.3 0.65	0.82*	0.6	0.75* 2	10	100						2	1	71
BC560B	TO-92 (97)	45	50	5	45	100	100	240	500*	2	5	0.3 0.65	0.82*	0.6	0.75* 2	10	100						2	1	71
BC560C	TO-92 (97)	45	50	5	45	100	100	450	900*	2	5	0.3 0.65	0.82*	0.6	0.75* 2	10	100						2	1	71
BCX58	TO-92 (97)	32	32	7	32	10	10	120	630	2	5							125	125	125	800	6	3/4	04	
BCX58-7	TO-92 (97)	32	32	7	32	10	10	80	1000	10	1							125	125	125	800	6	3/4	04	
BCX58-8	TO-92 (97)	32	32	7	32	10	10	120	220	2	5							125	125	125	800	6	3/4	04	
BCX58-9	TO-92 (97)	32	32	7	32	10	10	20	0.01	5	5							125	125	125	800	6	3/4	04	
BCX58-10	TO-92 (97)	32	32	7	32	10	10	180	310	2	5							125	125	125	800	6	3/4	04	
BCX59	TO-92 (97)	45	50	7	45	10	10	250	460	2	5							125	125	125	800	6	3/4	04	
BCX59-7	TO-92 (97)	45	50	7	45	10	10	160	630	10	1							125	125	125	800	6	3/4	04	
BCX59-8	TO-92 (97)	45	50	7	45	10	10	60	100	1	1							125	125	125	800	6	3/4	04	
BCX59-9	TO-92 (97)	45	50	7	45	10	10	100	100	1	1							125	125	125	800	6	3/4	04	

6501130 NATL SEMICOND, (DISCRETE)

28C 35526

D

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} [*] (V) Min	V _{EB} (V) Min	I _{CE} [*] I _{CB} (mA) Max	HFE h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) (V)	V _{CE} (SAT) (V) Max	V _{BE} (SAT) (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BCX59-10	TO-92 (97)		45	7		100 380 240 60	0.01 2 10 100	0.5	1.0	100		125	800		5	04
BCX78	TO-92 (97)		32	5		120 80 40	2 10 100	0.6	1.0	100						71
BCX78-7	TO-92 (97)		32	5		120 80 40	2 10 100	0.6	1.0	100						71
BCX78-8	TO-92 (97)		32	5		30 180 120 45	0.01 2 10 100	0.6	1.0	100						71
BCX78-9	TO-92 (97)		32	5		40 250 160 60	0.01 2 10 100	0.6	1.0	100						71
BCX78-10	TO-92 (97)		32	5		100 380 240 60	0.01 2 10 100	0.6	1.0	100						71
BCX79	TO-92 (97)		45	5		80 40	10 100	0.6	1.0	100						71
BCX79-7	TO-92 (97)		45	5		120 60	2 100	0.6	1.0	100						71
BCX79-8	TO-92 (97)		45	5		120 45	2 100	0.6	1.0	100						71
BCX79-9	TO-92 (97)		45	5		160 60 40 250	10 100 0.01 2	0.6	1.0	100						71

T-29-01

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 μA, V_{CE} = 20V, I_B = I_C = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B = I_C = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B = I_C = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B = I_C = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35527 D

T-29-01

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} ⁺ V _{CB} (V) Min	V _{CE0} ⁺ (V) Min	V _{EBO} (V) Min	I _{CE} ⁺ I _{CB} (mA) Max	HFE h _{fe} 1 kHz Min Max	I _C & V _{CE} (mA) (V) Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BCX79-10	TO-92 (97)		45	5		240 60 100 380	1000 100 0.01 630	1 1 5 5	0.6 1.0 100	100							71
BCY56	TO-18	45	45	5	100	40 100 125 40	10 2 500* 0.01	5 5 2 5	0.6 0.7* 2	2					5	1	04
BCY57	TO-18	25	20	5	100	200 200 240 100	10 5 2 0.01	5 5 5 5	0.6 0.7* 2	2					5	1	04
BCY58	TO-18		32	7	10 [†]	40 80 125	100 10 700*	1 1 2 5	0.35 0.7 0.55	10 100 2	6	125	10	800	6	4/1	04
BCY58-7	TO-18		32	7	10 [†]	40 80 175	100 10 350*	1 1 2 5	0.35 0.7 0.55	10 100 2	6	125	10	800	6	4/1	04
BCY58-8	TO-18		32	7	10 [†]	40 80	100 10	1 1	0.35 0.7	10 100	6	125	10	800	6	4/1	04
BCY58-9	TO-18		32	7	10 [†]	40 80 250	100 10 500*	1 1 2 5	0.35 0.7 0.55	10 100 2	6	125	10	800	6	4/1	04
BCY58-10	TO-18		32	7	10 [†]	40 80 350	100 10 700*	1 1 2 5	0.35 0.7 0.55	10 100 2	6	125	10	800	6	4/1	04
BCY59	TO-18		45	7	10 [†]	40 80 125	100 10 700*	1 1 2 5	0.35 0.7 0.55	10 100 2	6	125	10	800	6	4/1	04
BCY59-7	TO-18		45	7	10 [†]	40 80 125	100 10 250*	1 1 2 5	0.35 0.7 0.55	10 100 2	6	125	10	800	6	4/1	04
BCY59-8	TO-18		45	7	10 [†]	40 80 175	100 10 350*	1 1 2 5	0.35 0.7 0.55	10 100 2	6	125	10	800	6	4/1	04
BCY59-9	TO-18		45	7	10 [†]	40 80 250	100 10 500*	1 1 2 5	0.35 0.7 0.55	10 100 2	6	125	10	800	6	4/1	04

6501130 NATL SEMICOND, (DISCRETE)

28C 35528

7-33-01

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	VCES* VCBO (V) Min	VCEO (V) Min	VEBO (V) Min	ICES* ICBO (mA) Max	HFE h _{FE} 1 kHz* e Min Max	IC & VCE (mA) (V)	VCE(SAT) (V) Max	VBE(SAT) & VBE(ON)* e (V) Min Max		Cob (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
									IC (mA)	VCE (V)						
BCY59-10	TO-18		45	7	10†	40 80 350 700*	100 10 2	0.35 0.7	0.6 0.85 0.75 1.2 0.55 0.7*	10 100	6	125	800	6	4/1	04
BCY70	TO-18		40	5	10	40 45 50 15	0.1 1 1 1 1 50 1	0.25	0.6 0.9	10	6	250	420	6	5/6	71
BCY71	TO-18	45	45	5	500	40 80 90 100	0.01 0.1 1 1 1 600 10	0.25	0.6 0.9 1.2 50	10	6	200		2	6	71
BCY71A	TO-18	45	45	5	500	40 80 90 100	0.01 0.1 1 1 1 600 10	0.25	0.6 0.9 1.2 50	10	6	300	420	2	6	71
BCY72	TO-18	25	25	5	500	40 50	1 10	0.25	1.2 50	10	6	200	420	6	5/6	71
BD135	TO-126	45	45	5	100	25 40	500 2 50 2	0.5	1.0* 500	500		50	420	6	5/6	37
BD135-6	TO-126	45	45	5	100	40 25	150 2 500 2	0.5	500	500		50				37
BD135-10	TO-126	45	45	5	100	63 25	150 2 500 2	0.5	500	500		50				37
BD135-16	TO-126	45	45	5	100	100 25	150 2 500 2	0.5	500	500		50				37
BD136	TO-126	45	45	5	100	40 25	150 2 500 2	0.5	500	500		50				77
BD136-6	TO-126	45	45	5	100	40 25	150 2 500 2	0.5	500	500		50				77
BD136-10	TO-126	45	45	5	100	63 25	150 2 500 2	0.5	500	500		50				77
BD136-16	TO-126	45	45	5	100	100 25	150 2 500 2	0.5	500	500		50				77
BD137	TO-126	60	60	5	100	40 25	150 2 500 2	0.5	500	500		50				38

TEST CONDITIONS:

(1) IC = 200 μA, VCE = 5V, f = 1 kHz. (2) IC = 100 mA, VCC = 20V, IB¹ = IB² = 5 mA. (3) IC = 200 μA, VCE = 2V, f = 1 kHz. (4) IC = 100 mA, VCC = 10V, IB¹ = IB² = 10 mA. (5) IC = 10 mA, VCC = 3V, IB¹ = IB² = 1 mA. (6) IC = 100 μA, VCE = 5V, f = 1 kHz. (7) IC = 1 mA, VCE = 10V, f = 200 kHz. (8) IC = 1 mA, VCE = 5V, f = 1 kHz. (9) IC = 150 mA, VCC = 6V, IB¹ = IB² = 15 mA. (10) IC = 10 μA, VCE = 5V, f = WB.

Pro Electron Series

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35529 D

T-33-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CEO} (V) Min	V _{EBO} (V) Min	I _{CS} [*] I _{CB} (mA) Max	H _{FE} h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) & (V) 2	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD137-6	TO-126	60	60	5	100	40 100	150 2	0.5		500		50	50				38
BD137-10	TO-126	60	60	5	100	63 160	150 2	0.5		500		50	50				38
BD138	TO-126	60	60	5	100	40 160	150 2	0.5		500		50	50				78
BD138-6	TO-126	60	60	5	100	40 100	150 2	0.5		500		50	50				78
BD138-10	TO-126	60	60	5	100	63 160	150 2	0.5		500		50	50				78
BD139	TO-126	80	80	5	100	25 500	2	0.5	1.0*	500		50	50	420	6	5/6	39
BD139-6	TO-126	80	80	5	100	40 160	50 2	0.5	1.0*	500		50	50				39
BD139-10	TO-126	80	80	5	100	25 500	2	0.5	1.0*	500		50	50				39
BD140	TO-126	80	80	5	100	40 160	50 2	0.5	1.0*	500		50	50	420	6	5/6	79
BD157	TO-126		250		100 μA	30 240	50 10										36
BD158	TO-126		300		100 μA	30 240	50 10										36
BD159	TO-126		350		100 μA	30 240	50 10										36
BD185	TO-126		30		100 μA	40 500	2A 2	1.0	1.2*	2A							4F
BD186	TO-126		30		100 μA	40 500	2A 2	1.0	1.5*	2A							5F
BD187	TO-126		45		100 μA	40 500	2A 2	1.0	1.5*	2A							4F
BD188	TO-126		45		100 μA	40 500	2A 2	1.0	1.5*	2A							5F
BD189	TO-126		60		100 μA	40 500	2A 2	1.0	1.5*	2A							4F
BD190	TO-126		60		100 μA	40 500	2A 2	1.0	1.5*	2A							5F
BD201	TO-220	60	45	5	10 μA	30 3A	2 2	1.0	1.5*	3A		3	300	420	6	5/6	4A
BD202	TO-220	60	45	5	10 μA	30 3A	2 2	1.0	1.5*	3A		3	300	420	6	5/6	5A

6501130 NATL SEMICOND, (DISCRETE)

28C 35530

D

T-33-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} * V _{CB} (V) Min	V _{CE} (V) Min	V _{EB} (V) Min	I _{CB} * (mA) Max	H _{FE} h _{FE} 1 kHz* Min Max	I _C & V _{CE} (mA) (V)	V _{CE} (SAT) (V) Max	V _{BE} (SAT) & V _{BE} (ON)* (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD203	TO-220	60	60	5		30 30	2 1 2	1.0		3A		3	300				4A
BD204	TO-220	60	60	5	10 μA	30 30	2A 1A 1	1.0	1.5*	3A							5A
BD220	TO-220	70	70			30 30	120 1A 4	1.0	1.1*	500							4F
BD221	TO-220	40	40			30 30	120 1A 4	1.0	1.3*	1A							4F
BD222	TO-220	60	60			20 20	80 1.5A 4	1.0	1.5*	1.5A							4F
BD223	TO-220	70	70			30 30	120 300 4	1.0	1.1*	500							5F
BD224	TO-220	40	40			30 20	120 80 1.5A 4	1.0	1.3*	1A							5F
BD225	TO-220	60	60			20 20	80 1.5A 4	1.0	1.5*	1.5A							5F
BD233	TO-126	45	45		100 μA	25 40	1A 150 2	0.6	1.3*	1A		3	250	420	6	5/6	4F
BD234	TO-126	45	45		100 μA	25 40	1A 150 2	0.6	1.3*	1A		3	250	420	6	5/6	5F
BD235	TO-126	60	60		100 μA	25 40	1A 150 2	0.6	1.3*	1A		3	250	420	6	5/6	4F
BD236	TO-126	60	60		100 μA	25 40	1A 150 2	0.6	1.3*	1A		3	250	420	6	5/6	5F
BD237	TO-126	80	80		100 μA	25 40	1A 150 2	0.6	1.3*	1A		3	250	420	6	5/6	4F
BD238	TO-126	80	80		100 μA	25 40	1A 150 2	0.6	1.3*	1A		3	250	420	6	5/6	5F
BD239	TO-220	45	45		200 μA*	15 40	1A 200 4	0.7	1.3*	1A		3	200	420	6	5/6	4F
BD239A	TO-220	60	60		200 μA*	15 40	1A 200 4	0.7	1.3*	1A		3	200	420	6	5/6	4F
BD239B	TO-220	80	80		200 μA*	15 40	1A 200 4	0.7	1.3*	1A		3	200	420	6	5/6	4F
BD239C	TO-220	100	100		200 μA*	15 40	1A 200 4	0.7	1.3*	1A		3	200	420	6	5/6	4F
BD240	TO-220	45	45		200 μA*	15 40	1A 200 4	0.7	1.3*	1A		3	200	420	6	5/6	5F
BD240A	TO-220	80	80		200 μA*	15 40	1A 200 4	0.7	1.3*	1A		3	200	420	6	5/6	5F

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35531 D

T-33-01

Pro Electron Series

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} [*] V _{CB} [*] (V) Min	V _{CE} [*] (V) Min	V _{EB} [*] (V) Min	I _{CB} [*] I _{BO} [*] (mA) Max	HFE h _{FE} 1 kHz Min Max	I _C & V _{CE} (mA) & (V) Min Max	V _{CE(SAT)} (V) & V _{BE(ON)} (V) Max Min	I _C (mA) Min Max	C _{ob} (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD240B	TO-220	80	80		200 μA* 80	15 40	1A 4 200 4	0.7 1.3* 1A	200		3	420	6	5/6	5F
BD240C	TO-220	80	100		200 μA* 100	15 40	1A 4 200 4	0.7 1.3* 1A	200		3	420	6	5/6	5F
BD241	TO-220	80	45		200 μA* 45	10 25	3A 4 1A 4	1.3 1.8* 3A	500		3	420	6	5/6	4F
BD241A	TO-220	80	60		200 μA* 60	10 25	3A 4 1A 4	1.3 1.8* 3A	500		3	420	6	5/6	4F
BD241B	TO-220	80	80		200 μA* 80	10 25	3A 4 1A 4	1.3 1.8* 3A	500		3	420	6	5/6	4F
BD241C	TO-220	80	100		200 μA* 100	10 25	3A 4 1A 4	1.3 1.8* 3A	500		3	420	6	5/6	4F
BD242	TO-220	80	45		200 μA* 45	10 25	3A 4 1A 4	1.2 1.8* 3A	500		3	420	6	5/6	5E
BD242A	TO-220	80	60		200 μA* 60	10 25	3A 4 1A 4	1.2 1.8* 3A	500		3	420	6	5/6	5E
BD242B	TO-220	80	80		200 μA* 80	10 25	3A 4 1A 4	1.2 1.8* 3A	500		3	420	6	5/6	5E
BD242C	TO-220	80	100		200 μA* 100	10 25	3A 4 1A 4	1.2 1.8* 3A	500		3	420	6	5/6	5E
BD243	TO-220		45		400 μA* 45	30 15	300 4 3A 4		500		3				4A
BD243A	TO-220		60		400 μA* 60	30 15	300 4 3A 4		500		3				4A
BD243B	TO-220		80		400 μA* 80	30 15	300 4 3A 4		500		3				4A
BD243C	TO-220		100		400 μA* 100	30 15	300 4 3A 4		500		3				4A
BD244	TO-220		45		400 μA* 45	30 15	300 4 3A 4								4A
BD244A	TO-220		60		400 μA* 60	30 15	300 4 3A 4								5A
BD244B	TO-220		80		400 μA* 80	30 15	300 4 3A 4		500		3				5A
BD244C	TO-220		100		400 μA* 100	30 15	300 4 3A 4		500		3				5A
BD344	TO-126	60	60	5	500 60	60 40	50 1 200 1	0.4	200 50	20	50				78

6501130 NATL SEMICOND, (DISCRETE)

28C 35532

D Pro Electron Series

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CE} [*] I _{CE0} (mA) Max	HFE h _{FE} 1 kHz [*] Min	I _C & V _{CE} (mA) & (V) Max	V _{CE(SAT)} & V _{BE(ON)} [*] (V) & (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) & (V) Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD345	TO-126	60	5	500	60	50	0.4	200	20	50	50	50				38
BD346	TO-220	60		10 μA	40	140			200	4	250					5A
BD347	TO-220	60		10 μA	40	140			200	4	250					4A
BD348	TO-126	80	5	500	60	100	0.5	250	17	50	50	50				79
BD349	TO-126	80		500	50	250	0.5	1.5*	15	50	50	50				39
BD370A	TO-237 (91)	45		100	25	500	0.7	1.2*	30	50	200	200	420	6	5/6	78
BD370A-10	TO-237 (91)	80		100	25	500	0.7	1.2*	30	50	200	200	420	6	5/6	78
BD370A-16	TO-237 (91)	80		100	25	500	0.7	1.2*	30	50	200	200	420	6	5/6	78
BD370A-25	TO-237 (91)	80		100	25	500	0.7	1.2*	30	50	200	200	420	6	5/6	78
BD370B	TO-237 (91)	60		100	40	400	0.7	1.2*	30	50	200	200	420	6	5/6	78
BD370B-10	TO-237 (91)	80		100	25	500	0.7	1.2*	30	50	200	200	420	6	5/6	78
BD370B-16	TO-237 (91)	80		100	25	500	0.7	1.2*	30	50	200	200	420	6	5/6	78
BD370B-25	TO-237 (91)	80		100	25	500	0.7	1.2*	30	50	200	200	420	6	5/6	78
BD370C	TO-237 (91)	80		100	63	160	0.7	1.2*	30	50	200	200	420	6	5/6	78
BD370-6	TO-237 (91)	80		100	25	500	0.7	1.2*	30	50	200	200	420	6	5/6	78
BD370C-10	TO-237 (91)	80		100	25	500	0.7	1.2*	30	50	200	200	420	6	5/6	78
BD370C-16	TO-237 (91)	80		100	25	500	0.7	1.2*	30	50	200	200	420	6	5/6	78

T-33-01

TEST CONDITIONS:
 (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35533 D

T-33-01



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} [*] (V) Min	V _{EB} (V) Min	I _{CB} [*] (mA) Max	HFE h _{fe} 1 kHz Min	I _C & V _{CE} (mA) (V) Max	V _{CE} (SAT) & V _{BE} (ON) [*] (V) (V) Max Min		I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max		I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
								V _{CE} (SAT) (V) Max	V _{BE} (ON) [*] (V) Min			I _C (mA) Max	f _T (MHz) Min					
BD370D	TO-237 (91)	80	100		100	25 40	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	79	
BD370D-6	TO-237 (91)	80	100		100	25 40	500 2 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	79	
BD370D-10	TO-237 (91)	80	100		100	25 63	500 2 160 1	0.7	1.2*	1A	30	50	200	420	6	5/6	79	
BD371A	TO-237 (91)	45	45		100	25 40	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38	
BD371A-10	TO-237 (91)	45	45		100	25 63	500 2 160 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38	
BD371A-16	TO-237 (91)	45	45		100	25 100	500 2 250 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38	
BD371A-25	TO-237 (91)	45	45		100	25 180	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38	
BD371B	TO-237 (91)	80	60		100	25 40	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38	
BD371B-10	TO-237 (91)	80	60		100	25 63	500 2 160 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38	
BD371B-16	TO-237 (91)	80	60		100	25 100	500 2 250 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38	
BD371B-25	TO-237 (91)	80	60		100	25 160	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38	
BD371C	TO-237 (91)	80	80		100	25 40	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38	
BD371C-6	TO-237 (91)	80	80		100	25 40	500 2 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38	
BD371C-10	TO-237 (91)	80	80		100	25 63	500 2 160 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38	
BD371C-16	TO-237 (91)	80	80		100	25 100	500 2 250 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38	
BD371D	TO-237 (91)	80	100		100	25 40	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	39	
BD371D-6	TO-327 (91)	80	100		100	25 40	500 2 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	39	
BD371D-10	TO-237 (91)	80	100		100	25 63	500 2 160 1	0.7	1.2*	1A	30	50	200	420	6	5/6	39	
BD372A	TO-237 (90)	80	45		100	25 40	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78	

6501130 NATL SEMICOND, (DISCRETE)

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PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CS} [*] I _{CB0} (mA) Max	H _{FE} I _{hfe} @ 1 kHz Min Max	I _C & V _{CE} (mA) & (V)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) & (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD372A-10	TO-237 (90)	80	45		100	25 63	500 2 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372A-16	TO-237 (90)	80	45		100	25 100	500 2 250 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372A-25	TO-237 (90)	80	45		100	25 160	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372B	TO-237 (90)	80	60		100	25 40	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372B-10	TO-237 (90)	80	60		100	25 63	500 2 160 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372B-16	TO-237 (90)	80	60		100	25 100	500 2 250 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372B-25	TO-237 (90)	80	60		100	25 160	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372C	TO-237 (90)	80	80		100	25 40	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372C-6	TO-237 (90)	80	80		100	25 40	500 2 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372C-10	TO-237 (90)	80	80		100	25 63	500 2 160 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372C-16	TO-237 (90)	80	100		100	25 100	500 2 250 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372D	TO-237 (90)	80	100		100	25 40	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	79
BD372D-6	TO-237 (90)	80	100		100	25 40	500 2 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	79
BD372D-10	TO-237 (90)	80	100		100	25 63	500 2 160 1	0.7	1.2*	1A	30	50	200	420	6	5/6	79
BD373A	TO-237 (90)	80	45		100	25 40	500 2 400 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373A-10	TO-237 (90)	80	45		100	25 63	500 2 160 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373A-16	TO-237 (90)	80	45		100	25 100	500 2 250 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = 100 kHz.



Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35535 D

Pro Electron Series

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} * V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CS} * I _{CB0} (mA) Max	HFE h _{FE} @ 1 kHz* Min	I _C & V _{CE} (mA) (V) Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} * (V) (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD373A-25	TO-237 (90)	80	45		100	25 160	500 400 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373B	TO-237 (90)	80	80		100	25 40	500 400 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373B-10	TO-237 (90)	80	60		100	25 63	500 160 100 1	0.7	1.2*	1A	30	50	200	420	6	5/8	38
BD373B-16	TO-237 (90)	80	60		100	25 100	500 250 100 1	0.7	1.2*	1A	30	50	200	420	6	5/8	38
BD373B-25	TO-237 (90)	80	60		100	25 160	500 400 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373C	TO-237 (90)	80	80		100	25 40	500 400 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373C-6	TO-237 (90)	80	80		100	25 40	500 100 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373C-10	TO-237 (90)	80	80		100	25 63	500 160 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373C-16	TO-237 (90)	80	80		100	25 100	500 250 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373D	TO-237 (90)	80	100		100	25 40	500 400 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	39
BD373D-6	TO-237 (90)	80	100		100	25 40	500 100 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	39
BD373D-10	TO-237 (90)	80	100		100	25 63	500 160 100 1	0.7	1.2*	1A	30	50	200	420	6	5/6	39
BD375	TO-126	50	45		2 μA	20 40	1A 375 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD375-6	TO-126	50	45		2 μA	20 40	1A 100 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD375-10	TO-126	50	45		2 μA	20 63	1A 160 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD375-16	TO-126	50	45		2 μA	20 100	1A 250 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD375-25	TO-126	50	45		2 μA	20 150	1A 375 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD376	TO-126	50	45		2 μA	20 40	1A 375 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD376-6	TO-126	50	45		2 μA	20 40	1A 100 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78

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6501130 NATL SEMICOND, (DISCRETE)

28C 35536

D

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB} [*] (V) Min	V _{CEO} (V) Min	V _{EBO} (V) Min	I _{CB} [*] (μ A) Max	HFE		I _C & V _{CE}		V _{CE(SAT)} & V _{BE(ON)} [*]		C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
						h _{fe} 1 kHz [*] Min	h _{fe} 1 kHz [*] Max	I _C (mA)	V _{CE} (V)	Min	Max							
BD376-10	TO-126	50	45	45	2 μ A	20 63	150 150	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	78
BD376-16	TO-126	50	45	45	2 μ A	20 100	150 200	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	78
BD376-25	TO-126	50	45	45	2 μ A	20 150	150 375	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	78
BD377	TO-126	75	60	60	2 μ A	20 40	150 375	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	38
BD377-6	TO-126	75	60	60	2 μ A	20 40	100 150	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	38
BD377-10	TO-126	75	60	60	2 μ A	20 63	150 150	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	38
BD377-16	TO-126	75	60	60	2 μ A	20 100	150 250	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	38
BD377-25	TO-126	75	60	60	2 μ A	20 150	150 375	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	38
BD378	TO-126	75	60	60	2 μ A	20 40	150 375	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	78
BD378-6	TO-126	75	60	60	2 μ A	20 40	150 150	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	78
BD378-10	TO-126	75	60	60	2 μ A	20 40	100 150	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	78
BD378-16	TO-126	75	60	60	2 μ A	20 100	150 250	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	78
BD378-25	TO-126	75	60	60	2 μ A	20 150	150 375	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	78
BD379	TO-126	100	80	80	2 μ A	20 40	150 375	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	39
BD379-6	TO-126	100	80	80	2 μ A	20 40	100 150	1A 2	2	1.0	1.5*	30	50	200	420	6	5/6	39

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TEST CONDITIONS:
 (1) I_C = 200 μ A, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 μ A, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μ A, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μ A, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μ A, V_{CE} = 5V, f = WB.

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35537 D

Pro Electron Series

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE0} [*] (V) Min	V _{CE0} [*] (V) Min	V _{EB0} (V) Min	I _{CB0} [*] (mA) Max	V _{CB} (V)	H _{FE} h _{FE} 1 kHz [*] Min	H _{FE} h _{FE} 1 kHz [*] Max	I _C & V _{CE} (mA) & (V) Min	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD379-10	TO-126	100	80		2 μA	80	20	160	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	39
BD379-16	TO-126	100	80		2 μA	80	20	250	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	39
BD379-25	TO-126	100	80		2 μA	80	20	375	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	39
BD380	TO-126	100	80		2 μA	80	20	375	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	79
BD380-6	TO-126	100	80		2 μA	80	20	100	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	79
BD380-10	TO-126	100	80		2 μA	80	20	160	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	79
BD380-16	TO-126	100	80		2 μA	80	20	250	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	79
BD380-25	TO-126	100	80		2 μA	80	20	375	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	79
BD433	TO-126	22†	22	5	100 μA	22	50	475	2A 1	0.5	1.1*	2A		3	250	420	6	5/6	4E
BD434	TO-126	22†	22	5	100 μA	22	50	475	2A 1	0.5	1.1*	2A	30	3	250	420	6	5/6	5E
BD435	TO-126	32†	32	5	100 μA	32	50	475	2A 1	0.5	1.1*	2A	30	3	250	420	6	5/6	4E
BD436	TO-126	32†	32	5	100 μA	32	50	475	2A 1	0.5	1.1*	2A	30	3	250	420	6	5/6	5E
BD437	TO-126	45†	45	5	100 μA	45	40	236	2A 1	0.6	1.2*	2A	30	3	250	420	6	5/6	4E
BD438	TO-126	45†	45	5	100 μA	45	40	236	2A 1	0.6	1.2*	2A	30	3	250	420	6	5/6	5E
BD439	TO-126	60†	60	5	100 μA	60	25	236	2A 1	0.8	1.5*	2A	30	3	250	420	6	5/6	4E

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6501130 NATL SEMICOND, (DISCRETE)

28C 35538

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PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} * V _{CB0} (V) Min	V _{CEO} (V) Min	V _{EB0} (V) Min	I _{CB0} * (mA) Max	V _{CB} (V) Max	H _{FE} h _{FE} @ 1 kHz*	I _C & V _{CE} (mA) (V) Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)*} (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD440	TO-126	60†	60	5	100 μA	60	25 40 20	2A 500 10	0.8	1.5*	2A	80	3	250	420	6	5/6	5E
BD441	TO-126	80†	80	5	100 μA	80	15 40 15	2A 500 10	0.8	1.5*	2A	30	3	250	420	6	5/6	4E
BD442	TO-126	80†	80	5	100 μA	80	15 40 15	2A 500 10	0.8	1.5*	2A	30	3	250	420	6	5/6	5E
BD533	TO-220	80†	45	5	100 μA	45	25 40 20	2A 500 10	0.8	1.5*	2A	30	3	250	420	6	5/6	4E
BD534	TO-220	80†	45	5	100 μA	45	25 40 20	2A 500 10	0.8	1.5*	2A	30	3	250	420	6	5/6	5E
BD535	TO-220	80†	60	5	100 μA	60	25 40 20	2A 500 10	0.8	1.5*	2A	30	3	250	420	6	5/6	4E
BD536	TO-220	80†	60	5	100 μA	60	25 40 20	2A 500 10	0.8	1.5*	2A	30	3	250	420	6	5/6	5E
BD537	TO-220	80†	80	5	100 μA	80	15 40 15	2A 500 10	0.8	1.5*	2A	30	3	250	420	6	5/6	4E
BD538	TO-220	80†	80	5	100 μA	80	15 40 15	2A 500 10	0.8	1.5*	2A	30	3	250	420	6	5/6	5E
BD633	TO-220	45	45	5	200 μA†	45	25 40	1A 25	0.6	1.3*	1A	30	3	250	420	6	5/6	4F
BD634	TO-220	45	45	5	200 μA†	45	25 40	1A 25	0.6	1.3*	1A	30	3	250	420	6	5/6	5F
BD635	TO-220	60	60	5	200 μA†	60	25 40	1A 25	0.6	1.3*	1A	30	3	250	420	6	5/6	4F

TEST CONDITIONS:
 (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V.
 I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 10 μA.
 V_{CE} = 5V, f = WB.

Pro Electron Series

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6501130 NATL SEMICOND, (DISCRETE)

28C 35539 D

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Pro Electron Series

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} [*] V _{CB} (V) Min	V _{EB} (V) Min	I _{CB} [*] I _{BO} (mA) Max	V _{CB} (V) Max	HFE h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) & (V) Min Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD636	TO-220	60	60	5	200 μA†	60	25 40	1A 25	0.6	1.3*	1A	30	3	250	420	6	5/6	5F
BD637	TO-220	100	80	5	200 μA†	100	25	1A 25	0.6	1.3*	1A	30	3	250	420	6	5/6	4F
BD638	TO-220	100	80	5	200 μA†	100	25	1A 25	0.6	1.3	1A	30	3	250	420	6	5/6	5F
BD675	TO-126	45	45		200 μA	45	750	1.5A 3	2.5	2.5*	1.5A		1	1.5A				4J
BD675A	TO-126	45	45		200 μA	45	750	2A 3	2.8	2.5*	2A		1	1.5A				4J
BD676	TO-126	45	45		200 μA	45	750	1.5A 3V	2.5	2.5*	1.5A		1	1.5A				5J
BD676A	TO-126	45	45		200 μA	45	750	2A 3V	2.8	2.5*	2A		1	1.5A				5J
BD677	TO-126	60	60		200 μA	60	750	1.5A 3V	2.5	2.5*	1.5A		1	1.5A				4J
BD677A	TO-126	60	60		200 μA	60	750	2A 3V	2.8	2.5*	2A		1	1.5A				4J
BD678	TO-126	60	60		200 μA	60	750	1.5A 3V	2.5	2.5*	1.5A		1	1.5A				5J
BD678A	TO-126	60	60		200 μA	60	750	2A 3V	2.8	2.5*	2A		1	1.5A				5J
BD679	TO-126	80	80		200 μA	80	750	1.5A 3V	2.5	2.5*	1.5A		1	1.5A				4J
BD679A	TO-126	80	80		200 μA	80	750	2A 3V	2.8	2.5*	2A		1	1.5A				4J
BD680	TO-126	80	80		200 μA	80	750	1.5A 3V	2.5	2.5*	1.5A		1	1.5A				4J
BD680A	TO-126	80	80		200 μA	80	750	2A 3V	2.8	2.5*	2A		1	1.5A				4J
BD681	TO-126	100	100		200 μA	100	750	1.5A 3V	2.5	2.5*	1.5A		1	1.5A				5J
BD682	TO-126	100	100		200 μA	100	750	2A 3V	2.5	2.5*	1.5A		1	1.5A				5J
BD733	TO-220	25	25	5	200 μA†	25	50 40	2A 20	0.6	1.1*	2A		1	1.5A				4F
BD734	TO-220	25	25	5	200 μA†	25	50 40	2A 20	0.6	1.1*	2A		1	1.5A				5E
BD735	TO-220	35	35	5	200 μA†	35	40	2A 20	0.6	1.1*	2A		1	1.5A				4F
BD736	TO-220	35	35	5	200 μA†	35	40	2A 20	0.6	1.1*	2A		1	1.5A				5E
BD737	TO-220	45	45	5	200 μA†	45	40	2A 20	0.8	1.1*	2A		1	1.5A				4F
BD738	TO-220	45	45	5	200 μA†	45	40	2A 20	0.8	1.1*	2A		1	1.5A				5E
BD795	TO-220		45		100	45	40	2A 20	0.8	1.1*	2A		1	1.5A				4E
BD796	TO-220		45		100	45	25	1A 3A	1.0	1.6*	3A	3	3	250				5E
BD797	TO-220		60		100 μA	60	40 25	1A 3A	1.0	1.6*	3A	3	3	250				4E

6501130 NATL SEMICOND, (DISCRETE)

28C 35540

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PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} [*] (V) Min	V _{EB} [*] (V) Min	I _{CB} [*] (mA) Max	V _{CB} (V)	h _{FE} 1 kHz [*] Min Max	I _C (mA) & V _{CE} (V)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD798	TO-220		60		100 μA	60	40	1A 2	1.0	1.6*	3A		3				5E
BD799	TO-220		80		100 μA	80	30	1A 2	1.0	1.6*	3A		3				4E
BD800	TO-220		80		100 μA	80	30	1A 2	1.0	1.6*	3A		3				5E
BD801	TO-220		100		100 μA	100	30	1A 2	1.0	1.6*	3A		3				4E
BD802	TO-220		100		100 μA	100	30	1A 2	1.0	1.6*	3A		3				5E
BD895	TO-220		45		200 μA	45	750	3A 3		2.5*	3A		1				4K
BD895A	TO-220		45		200 μA	45	750	4A 3		2.5*	4A		1				4K
BD896	TO-220		45		200 μA	45	750	3A 3		2.5*	3A		1				5K
BD896A	TO-220		45		200 μA	45	750	4A 3		2.5*	4A		1				5K
BD897	TO-220		60		200 μA	60	750	3A 3		2.5*	3A		1				4K
BD897A	TO-220		60		200 μA	60	750	4A 3		2.5*	4A		1				4K
BD898	TO-220		60		200 μA	60	750	3A 3		2.5*	3A		1				5K
BD898A	TO-220		60		200 μA	60	750	4A 3		2.5*	4A		1				5K
BD899	TO-220		80		200 μA	80	750	3A 3		2.5*	3A		1				4K
BD899A	TO-220		80		200 μA	80	750	4A 3		2.5*	4A		1				4K
BD900	TO-220		80		200 μA	80	750	3A 3		2.5*	3A		1				5K
BD900A	TO-220		80		200 μA	80	750	4A 3		2.5*	4A		1				5K
BD901	TO-220		100		200 μA	100	750	3A 3		2.5*	3A		1				4K
BD902	TO-220		100		200 μA	100	750	4A 3		2.5*	4A		1				4K
BDX33	TO-220		45		1 mA	45	750	4A 3		2.5*	4A		20				4K
BDX33A	TO-220		60		1 mA	60	750	4A 3		2.5*	4A		20				4K
BDX33B	TO-220		80		1 mA	80	750	3A 3		2.5*	3A		20				4K
BDX33C	TO-220		100		1 mA	100	750	3A 3		2.5*	3A		20				4K
BDX33D	TO-220		120		1 mA	120	750	3A 3		2.5*	3A		20				4K
BDX34	TO-220		45		1 mA	45	750	4A 3		2.5*	4A		20				5K
BDX34A	TO-220		60		1 mA	60	750	4A 3		2.5*	4A		20				5K
BDX34B	TO-220		80		1 mA	80	750	3A 3		2.5*	3A		20				5K

TEST CONDITIONS:
 (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

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6501130 NATL SEMICOND, (DISCRETE)

28C 35541 D

7-31-01

Pro Electron Series

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} [*] V _{CB} (V) Min	V _{EB} (V) Min	ICES [*] I _{CB} (mA) Max	HFE h _{fe} @ 1 kHz [*] Min Max	I _C & V _{CE} (mA) (V) Min Max	V _{CE} (SAT) (V) Max	V _{BE} (ON) [*] (V) Min Max	I _C (mA) Min Max	C _{ob} (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BDX34C	TO-220	100	100	4	1 mA	750	3A 3	2.5*	2.5*	3A		20				5K
BDX34D	TO-220	120	120	4	1 mA	750	3A 3	2.5*	2.5*	3A		20				5K
BF167	TO-72 (28)	40	30	4	100†	26	4 10	0.84*	0.84*	4						45
BF180	TO-72 (25)	30	20	3	100	13	2 10									41
BF181	TO-72 (25)	30	20	3	100	13	2 10									41
BF194	TO-92 (98)	Same as BF254, see page 5-33 for explanation														
BF195	TO-92 (98)	Same as BF255, see page 5-33 for explanation														
BF196	TO-92 (98)	Same as BF198, see below for explanation														
BF197	TO-92 (98)	Same as BF199, see below for explanation														
BF198	TO-92 (98)	40	30	4	100	26	4 10		0.88*	4						45
BF199	TO-92 (98)	40	25	4	100	36	7 10					1100 typ				47
BF200	TO-72 (25)	30	20	3	100	15	3 10									41
BF233-2	TO-92 (96)	30	30	4	100	40	1 10	0.65	0.74*	1	1.0	150				49
BF233-3	TO-92 (96)	30	30	4	100	60	1 10	0.65	0.74*	1	1.0	150				49
BF233-4	TO-92 (96)	30	30	4	100	90	1 10	0.65	0.74*	1	1.0	150				49
BF233-5	TO-92 (96)	30	30	4	100	140	1 10	0.65	0.74*	1	1.0	150				49
BF237	TO-92 (98)	45	30	4	100			0.25		10						47
BF238	TO-92 (98)	45	30	4	100			0.25		10						47
BF240	TO-92 (98)	40	40	4	100	67	1 10	0.65	0.74*	1	0.34			3.5	7	47
BF241	TO-92 (98)	40	40	4	100	36	1 10	0.65	0.74*	1	0.34			3.5	7	47

6501130 NATL SEMICOND, (DISCRETE)

28C 35542

D

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} * V _{CE0} (V)		V _{BE0} (V)		I _{CE} * I _{CE0} (mA)		h _{FE} h _{FE} @ 1 kHz*		I _C & V _{CE} (V)		V _{CE(SAT)} (V) & V _{BE(ON)} * (V)		f _T (MHz)		t _{off} (ns)		NF (dB)		Test Conditions	Process No.
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max		
BF254	TO-92 (98)	30	20	5	20	100	20	67	220	1	10	0.65	0.74*	1				3.5		7	46
BF255	TO-92 (98)	30	20	5	20	100	20	36	125	1	10	0.65	0.74*	1				3.5		7	46
BF257	TO-39	100	100	5	100	50	100	25	30	30	10	1.0	0.74*	30				3.5		7	48
BF258	TO-39	250	250	5	200	50	200	25	30	30	10	1.0	0.74*	30				3.5		7	48
BF259	TO-39	300	300	5	250	50	250	25	30	30	10	1.0	0.74*	30				3.5		7	48
BF457	TO-126	100	100	5	100	50	100	25	30	30	10	1.0	0.74*	30				3.5		7	48
BF458	TO-126	250	200	5	200	50	200	25	30	30	10	1.0	0.74*	30				3.5		7	48
BF459	TO-126	300	300	5	250	50	250	25	30	30	10	1.0	0.74*	30				3.5		7	48
BFX13	TO-18	20	15	5	15	50	15	10	100	2	2	0.2	0.78	1	150			10		8	66
BFX29	TO-5	20	15	5	50	50	50	40	150	10	10	0.4	1.3	150						9	63
BFX30	TO-5	65	65	5	50	50	50	10	150	0.4	0.4	0.9	0.9	10						4	63
BFX37	TO-18	60	60	6	50	20†	50	100	1	5	5	0.4	1.0	50						1	62
BFX65	TO-18	45	45	6	40	10*	40	100	0.1	5	5	0.25	0.9	10						1	62

TEST CONDITIONS: (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B = I_C = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B = I_C = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B = I_C = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B = I_C = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

T-31-01

Pro Electron Series

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35543 D
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PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE0} [*] (V)		V _{BE0} (V)		I _{CB0} [*] (nA)		H _{FE} @ 1 kHz [*]		I _C & V _{CE} (V)		V _{CE(SAT)} & V _{BE(ON)} [*] (V)		C _{ob} (pF)		f _T (MHz)		t _{off} (ns)	NF (dB)	Test Conditions	Process No.
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max				
BFX84	TO-39	45	45	6	6	500	100	15	20	1A	10	0.15	1.2	10	12	50	50	360		9	14
BFX85	TO-39	45	45	6	6	50	80	15	30	1A	10	0.15	1.2	10	12	50	50	360		9	14
BFX86	TO-39	45	45	6	6	50	30	15	30	1A	10	0.15	1.2	10	12	50	50	360		9	14
BFX87	TO-5	45	50	6	6	50	40	25	40	500	10	0.4	1.3	150	12	100	50	150		9	63
BFX88	TO-5	45	40	6	6	50	30	25	40	500	10	0.4	1.3	150	12	100	50	150		9	63
BFY39	TO-18	45	25	5	5	50	30	35	400	10	10	1.0	1.0	10		150	10				23
BFY39-1	TO-18	45	25	5	5	50	30	35	110	10	10	1.0	1.0	10		150	10				23
BFY39-2	TO-18	45	25	5	5	50	30	100	200	10	10	1.0	1.0	10		150	10				23
BFY39-3	TO-18	45	25	5	5	50	30	180	400	10	10	1.0	1.0	10		150	10				23
BFY50	TO-18	80	35	6	6	500	80	20	30	10	10	0.1	1.2	10	12	60	50	360		9	14
BFY51	TO-39	60	30	6	6	500	60	30	40	10	10	0.1	1.2	10	12	60	50	360		9	14
BFY52	TO-39	40	20	6	6	500	60	30	60	10	10	0.1	1.2	10	12	60	50	360		9	14
BFY56	TO-39	80	45	5	5	50	50	15	20	1	10	0.3	1.5	150	25	40	50				14

6501130 NATL SEMICOND, (DISCRETE)

28C 35544

D

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE0} [*] (V) Min	V _{CE0} [*] (V) Max	V _{BE0} (V) Min	V _{BE0} (V) Max	I _{CB0} [*] (mA) Max	I _{CB0} [*] (mA) Min	HFE I _{re} 1 kHz [*] Min	HFE I _{re} 1 kHz [*] Max	I _C & V _{CE} (mA) & (V)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BFY72	TO-39	28	50	5	20	40*	0.1 1 10 10 10 10 150 500	15 20 30 40 15	0.1 1 10 10 10 10 500	0.25	1.2	150	8	50	50	50	19				19
BFY76	TO-18	45	45	6	30	20	0.01 0.5 5 5	30 80 140	0.01 0.5 5 5	0.35	1.6	500	6								
BSX21	TO-18	80	80	7	60	50	4 3	20	4 3	1.0	0.9	4	20	60	60	4	07				07
BSX45-6	TO-39	80*	80*	7	60	10*	100	40	100	1.0	2.0	1A	20	60	60	50	14				14
BSX45-10	TO-39	80*	80*	7	60	10*	100	63	160	1.0	2.0	1A	20	60	60	50	14				14
BSX45-16	TO-39	80*	80*	7	60	10*	100	100	250	1.0	2.0	1A	20	60	60	50	14				14
BSX46-6	TO-39	100*	100*	7	60	10*	100	40	100	1.0	2.0	1A	25	60	60	50	12				12
BSX46-10	TO-39	100*	100*	7	60	10*	100	63	160	1.0	2.0	1A	25	60	60	50	12				12
BSX46-16	TO-39	100*	100*	7	60	10*	100	100	250	1.0	2.0	1A	25	60	60	50	12				12
BSX48	TO-18	50	50	5	20	120	100	17	100	1.5	1.5	500	6	250	30	30	19				19
BSX88	TO-18	40	40	5	20	25	0.5	15	0.5	0.72	0.8	10	6	300	10	10	21				21
BSY38	TO-18	20	20	5	20	100	60 15	30 15	60 45	0.25 0.6	0.7 1.5	10 100	5	200	10	45	21			16	21
BSY39	TO-18	20	20	5	20	100	120 70	40 20	120 70	0.25 0.6	0.7 1.5	10 100	5	200	10	45	21			16	21
BSY51	TO-18	60	60	5	30	100	150	100	300	1.0	1.3	150	9	130	50	50	19				19
BSY52	TO-18	60	60	5	30	100	150	100	300	1.0	1.3	150	9	130	50	50	19				19
BSY53	TO-18	75	75	7	60	10	0.1 10 10	20 35 40	0.1 10 10	0.6	1.3	150	9	150	50	50	19				19

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TEST CONDITIONS:
 (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35545 D

T-31-01



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} [*] (V)		V _{BE0} (V)		I _{CE0} [*] (mA)		HFE _{hfe} @ 1 kHz [*]		I _C & VCE (V)		V _{CE(SAT)} (V) & V _{BE(ON)} [*] (V)		C _{ob} (pF)		f _T (MHz)		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max						
BSY54	TO-18	30	75	7	60	10	35	75	100	10	0.1	0.6	1.3	9	150	50	19				

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

6501130 NATL SEMICOND, (DISCRETE)

28C 35546

T-31-01

Pro Electron Series

PRO ELECTRON SERIES (JFET)



Type No.	Case Style	BV _{GSD} (V) @ I _G Min	I _{GSS} I _{DGD} (mA) @ V _{GD} Max (V)	V _P (V) @ V _{DS} Min Max (V)	I _D (nA)	V _{GS} (V) @ V _{GS} Min Max (V)	I _D (μA)	I _{DSS} (mA) @ V _{DS} Min Max (V)	R _e (V _{FS}) (mmho) @ f Min Max (MHz)	C _{iss} (pF) @ V _{DS} Typ (V)	V _{GS} (V)	C _{rss} (pF) @ V _{DS} Typ (V)	V _{GS} (V)	NF (dB) @ R _G = 1k f (MHz) * Max Typ	Process No.	Pkg. No.
BF244A	TO-92	30	5	5 8	10	4 2.2 15	200	2 6.5 15	3 6.5 .001	4 20	-1	1.1 20	-1	1.5 100	50	74
BF244B	TO-92	30	5	5 8	10	1.6 3.8 15	200	6 15 15	3 6.5 .001	4 20	-1	1.1 20	-1	1.5 100	50	74
BF244C	TO-92	30	5	5 8	10	3.2 7.5 15	200	12 25 15	3 6.5 .001	4 20	-1	1.1 20	-1	1.5 100	50	74
BF245A	TO-92	30	5	5 8	10	4 2.2 15	200	2 6.5 15	3 6.5 .001	4 20	-1	1.1 20	-1	1.5 100	50	77
BF245B	TO-92	30	5	5 8	10	1.6 3.8 15	200	6 15 15	3 6.5 .001	4 20	-1	1.1 20	-1	1.5 100	50	77
BF245C	TO-92	30	5	5 8	10	3.2 7.5 15	200	12 25 15	3 6.5 .001	4 20	-1	1.1 20	-1	1.5 100	50	77
BF246A	TO-92	25	5	6 14.5	15	1.5 4.0 15	200	30 80 15	8 .001 11 15	0 3.5 15	0	3.5 15	0	7.5 800	51	74
BF246B	TO-92	25	5	6 14.5	15	3.0 7.0 15	200	60 140 15	8 .001 11 15	0 3.5 15	0	3.5 15	0	7.5 800	51	74
BF246C	TO-92	25	5	6 14.5	15	5.5 12 15	200	110 250 15	8 .001 11 15	0 3.5 15	0	3.5 15	0	7.5 800	51	74
BF247A	TO-92	25	5	6 14.5	15	1.5 4.0 15	200	30 80 15	8 .001 11 15	0 3.5 15	0	3.5 15	0	7.5 800	51	77
BF247B	TO-92	25	5	6 14.5	15	3.0 7.0 15	200	60 140 15	8 .001 11 15	0 3.5 15	0	3.5 15	0	7.5 800	51	77
BF247C	TO-92	25	5	6 14.5	15	5.5 12 15	200	110 250 15	8 .001 11 15	0 3.5 15	0	3.5 15	0	7.5 800	51	77
BF256A	TO-92	30	5	5 20	10	5 7.5 15	200	3 7 15	4.5 .001	7 20	-1	.7 20	-1	40* 10*	50	77
BF256B	TO-92	30	5	5 20	10	5 7.5 15	200	6 13 15	4.5 .001	7 20	-1	.7 20	-1	40* 10*	50	77
BF256C	TO-92	30	5	5 20	10	5 7.5 15	200	11 18 15	4.5 .001	7 20	-1	.7 20	-1	40* 10*	50	77
BC264A	TO-92	30	10	5 15	10	2 1.2 15	1000	2 4.5 15	2.5 .001	4.0 15	-1	1.2 15	-1	40* 10*	50	77
BC264B	TO-92	30	10	5 15	10	4 1.4 15	1500	3.5 6.5 15	3.0 .001	4.0 15	-1	1.2 15	-1	40* 10*	50	77
BC264C	TO-92	30	10	5 15	10	5 1.5 15	2500	5.0 8.0 15	3.5 .001	4.0 15	-1	1.2 15	-1	40* 10*	50	77
BC264D	TO-92	30	10	5 15	10	6 1.6 15	3500	7.0 12.0 15	4.0 .001	4.0 15	-1	1.2 15	-1	40* 10*	50	77

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